

## 0.37 Ω, Low THD and Capacitance, Dual DPDT / Quad SPDT Analog Switch

### DESCRIPTION

The DG2525, is a four-channel single-pole double-throw (SPDT) analog switch with two control inputs. It is also known as a two-channel double-pole double-throw (DPDT) configuration. The part is designed to operate from 1.8 V to 5.5 V single power rail. All switches conduct equally well in both directions, offering rail to rail signal switching and can be used both as multiplexers as well as de-multiplexers.

The DG2525 offers low leakage, parasitic capacitance, and highly matched low and flat switch resistance over the full signal range. It features break-before-make switching and low control logic threshold. The part exhibits high bandwidth and excellent total harmonic distortion (THD). It is ideal for both analog and digital signal switching in space constrain applications requiring high performance and efficient use of board space.

The DG2525 comes in a small miniQFN-16 lead package of 2.6 mm x 1.8 mm x 0.55 mm.

### BENEFITS

- Low and flat resistance
- Excellent total harmonic distortion
- Low leakage and parasitic capacitance
- Low voltage control interface

### FEATURES

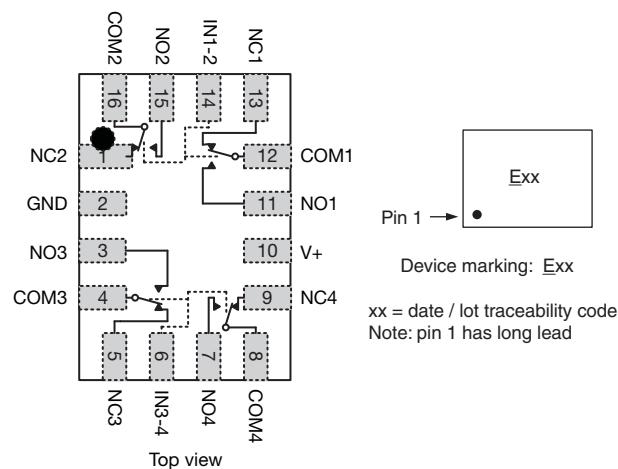
- 1.8 V to 5.5 V single supply operation
- Low resistance: 0.4 Ω/typ. at 2.7 V
- Highly flat and matched  $R_{ON}$
- Low parasitic capacitance,  $C_{ON} = 26 \text{ pF}$ ,  $C_{OFF} = 14.5 \text{ pF}$
- Switch off leakage: 5 pA at  $V_+ = 3.3 \text{ V}$ , 40 pA at  $V_+ = 5.5 \text{ V}$
- High bandwidth: 310 MHz
- -100 dB THD + N at 1 kHz, 0.9 V<sub>RMS</sub>,  $R_{LOAD} = 32 \Omega$
- Guaranteed logic high 1.2 V, logic low 0.3 V
- Break before make switching
- Signal swing over  $V_+$  capable
- Power down protection
- Latch up current: 300 mA (JESD78)
- ESD / HBM: > 6 kV
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)


**RoHS**  
COMPLIANT

### APPLICATIONS

- Smart phones and tablets
- Portable instrumentation
- Audio and video signal switching
- Modems and peripherals
- Data storage
- Wireless pins
- Relay replacement

### FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



### TRUTH TABLE

LOGIC	NC1, 2, 3, and 4	NO1, 2, 3, and 4
0	On	Off
1	Off	On

**ORDERING INFORMATION**

TEMPERATURE RANGE	PACKAGE	PART NUMBER	MIN. ORDER / PACK. QUANTITY
-40 °C to +85 °C lead (Pb)-free	miniQFN-16	DG2525DN-T1-GE4	Tape and reel, 3000 units

**ABSOLUTE MAXIMUM RATINGS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

PARAMETER	SYMBOL	LIMIT	UNIT
Reference to GND	V+	-0.3 to +6	V
	IN, COM, NC, NO <sup>a</sup>	-0.3 to (V+ + 0.3)	
Current (any terminal except NO, NC, or COM)		30	mA
Continuous current (NO, NC, or COM)		± 300	
Peak current (pulsed at 1 ms, 10 % duty cycle)		± 500	
Storage temperature (D suffix)		-65 to +150	°C
Package solder reflow conditions <sup>d</sup>	miniQFN-16	250	
Power dissipation (packages) <sup>b</sup>	miniQFN-16 <sup>c</sup>	525	mW

**Notes**

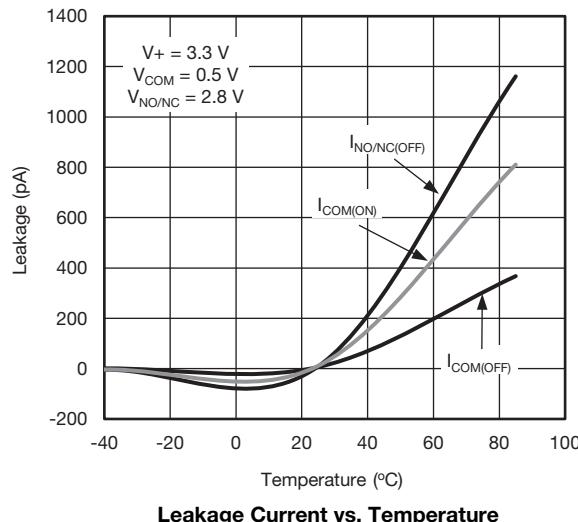
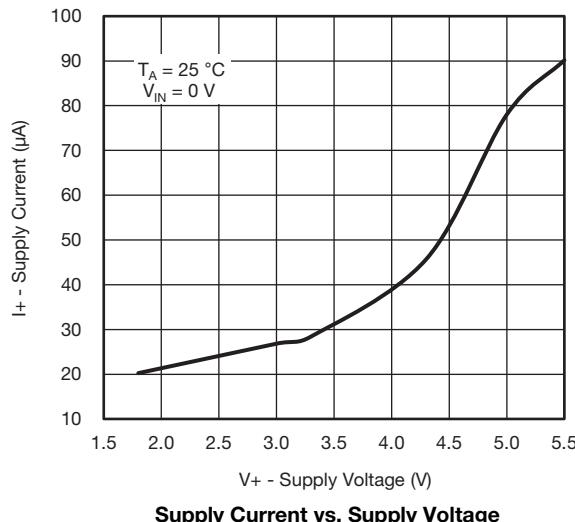
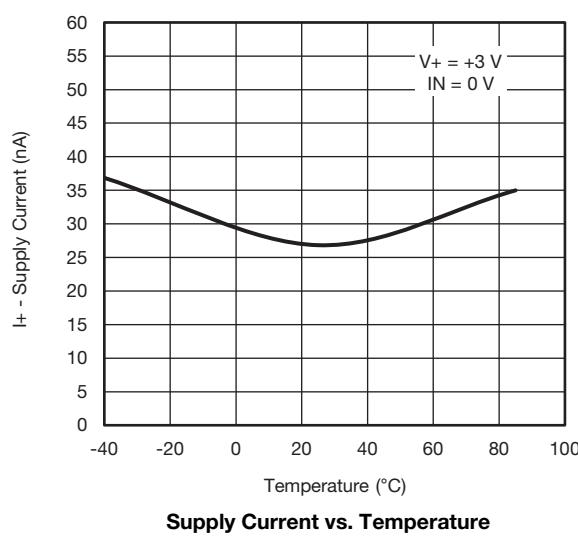
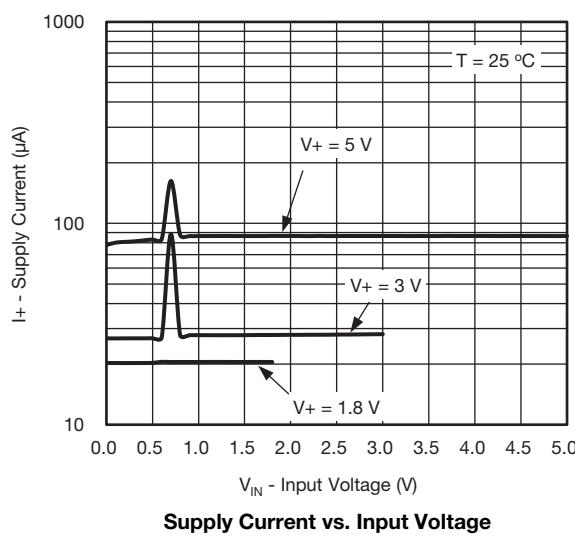
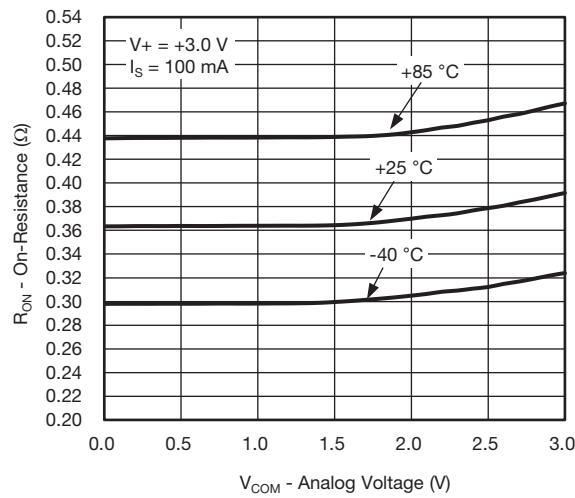
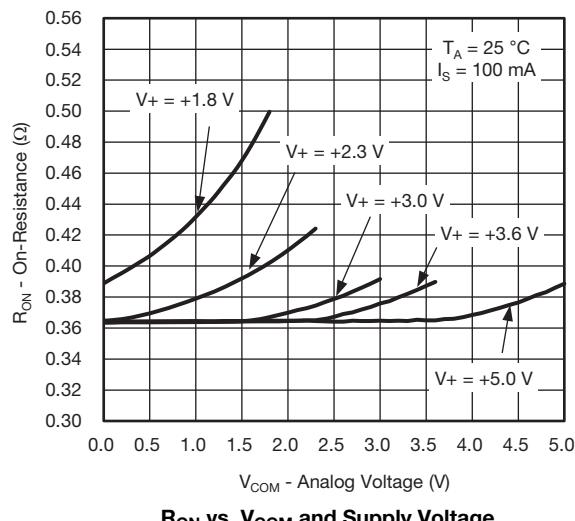
- a. Signals on NC, NO, or COM, or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
- b. All leads welded or soldered to PC board.
- c. Derate 6.6 mW/°C above 70 °C.
- d. Manual soldering with iron is not recommended for leadless components. The miniQFN-16 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper lip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

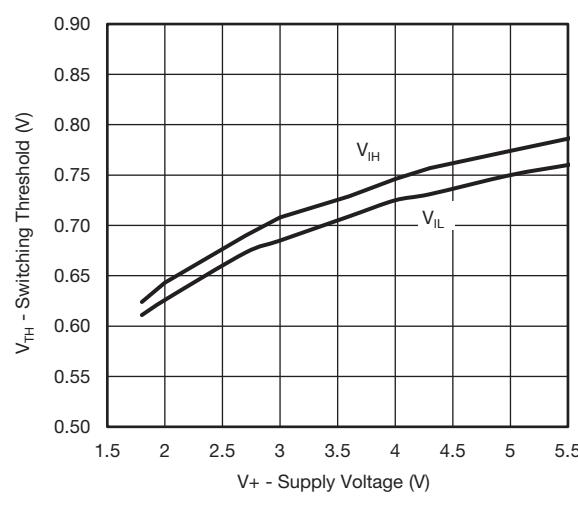
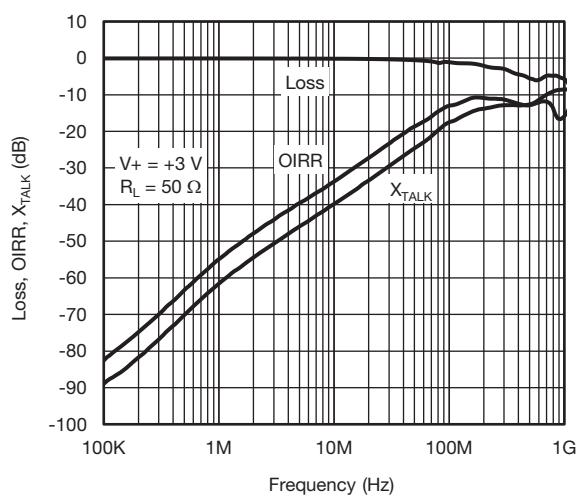
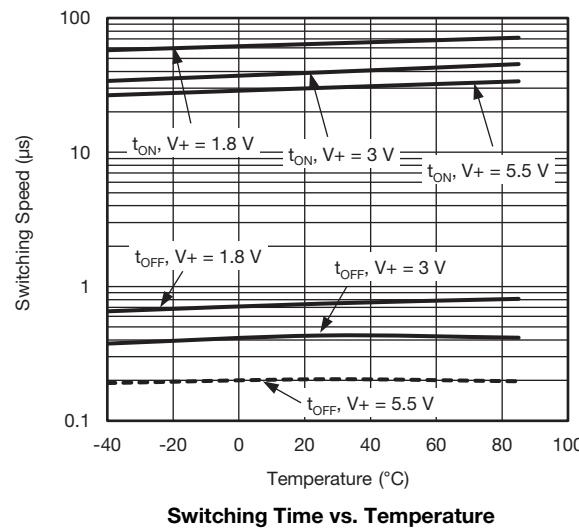
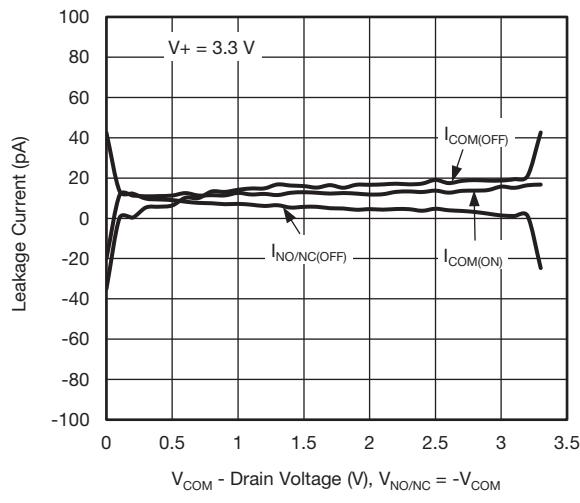
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

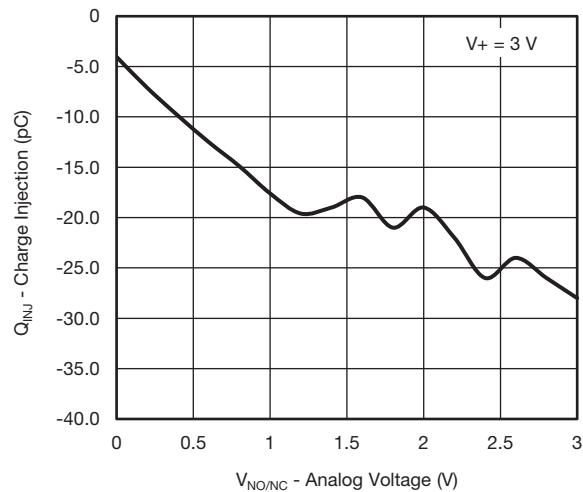
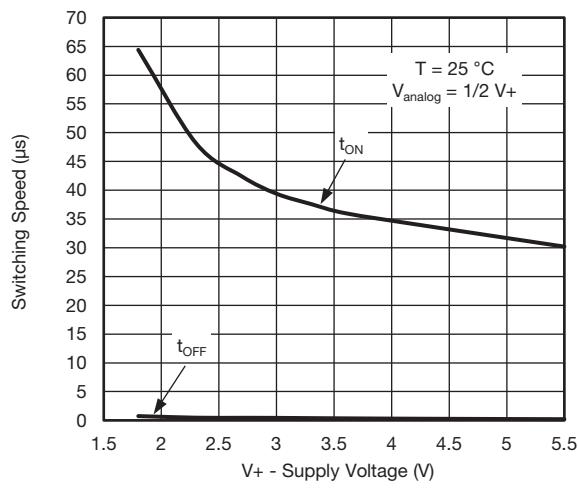
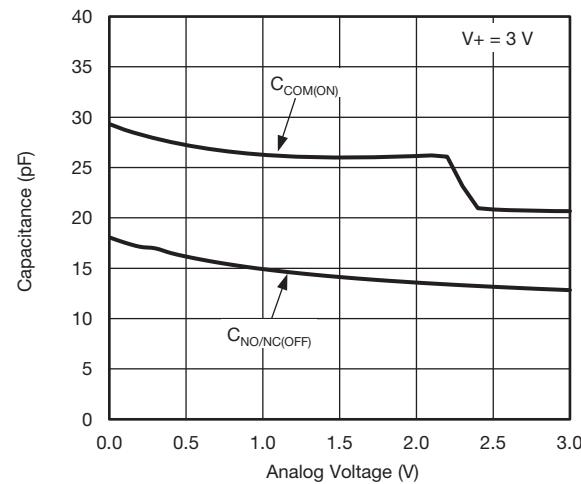
<b>SPECIFICATIONS</b> ( $V_+ = 3$ V)								
<b>PARAMETER</b>	<b>SYMBOL</b>	<b>TEST CONDITIONS</b> unless otherwise specified $V_+ = 3$ V, $\pm 10\%$ , $V_{IN} = 0.5$ or $1.4$ V <sup>e</sup>	<b>TEMP.<sup>a</sup></b>	<b>LIMITS</b>			<b>UNIT</b>	
				<b>MIN.<sup>b</sup></b>	<b>TYP.<sup>c</sup></b>	<b>MAX.<sup>b</sup></b>		
<b>Analog Switch</b>								
Analog signal range <sup>d</sup>	$V_{NO}$ , $V_{NC}$ , $V_{COM}$		Full	0	-	$V_+$	V	
On-resistance	$R_{ON}$	$V_+ = 2.7$ V, $V_{COM} = 0$ to $2.7$ V, $I_{NO}$ , $I_{NC} = 100$ mA	Room	-	0.37	0.5	$\Omega$	
			Full	-	-	0.6		
$R_{ON}$ flatness <sup>d</sup>	$R_{ON}$ flatness	$V_+ = 2.7$ V, $V_{COM} = 0$ to $V_+$ , $I_{NO}$ , $I_{NC} = 100$ mA	Full	-	0.03	0.08		
$R_{ON}$ match <sup>d</sup>	$\Delta R_{ON}$		Room	-	0.05	-		
Switch off leakage current	$I_{NO(off)}$ , $I_{NC(off)}$	$V_+ = 5.5$ V, $V_{NO}$ , $V_{NC} = 0.5$ V / 4 V, $V_{COM} = 4$ V / 0.5 V	Room	-1	0.04	1	$nA$	
	$I_{COM(off)}$		Full	-5	-	5		
			Room	-1	0.17	1		
			Full	-5	-	5		
Channel-on leakage current	$I_{COM(on)}$	$V_+ = 5.5$ V, $V_{NO}$ , $V_{NC} = V_{COM} = 0.5$ V / 4 V	Room	-1	0.17	1		
			Full	-5	-	5		
<b>Digital Control</b>								
Input high voltage	$V_{INH}$		Full	1.2	-	-	V	
Input low voltage	$V_{INL}$			-	-	0.3		
Input capacitance	$C_{IN}$		Full	-	5	-	pF	
Input current	$I_{INL}$ or $I_{INH}$	$V_{IN} = 0$ or $V_+$	Full	-1	-	1	$\mu A$	
<b>Dynamic Characteristics</b>								
Turn-on time	$t_{ON}$	$V_{NO}$ or $V_{NC} = 1.5$ V, $R_L = 50$ $\Omega$ , $C_L = 35$ pF	Room	-	38	60	$\mu s$	
Turn-off time	$t_{OFF}$		Full	-	-	70		
Break-before-make time	$t_d$		Room	-	0.43	1		
Charge injection <sup>d</sup>	$Q_{INJ}$		Full	-	-	3		
-3 dB bandwidth	BW	$R_L = 50$ $\Omega$ , $C_L = 5$ pF	Room	1	-	-	$MHz$	
Off-isolation <sup>d</sup>	OIRR	$R_L = 50$ $\Omega$ , $C_L = 5$ pF, $f = 100$ kHz	Room	-	-82	-		
		$R_L = 50$ $\Omega$ , $C_L = 5$ pF, $f = 1$ MHz		-	-55	-		
Crosstalk <sup>d, f</sup>	$X_{TALK}$	$R_L = 50$ $\Omega$ , $C_L = 5$ pF, $f = 100$ kHz		-	-89	-		
		$R_L = 50$ $\Omega$ , $C_L = 5$ pF, $f = 1$ MHz		-	-61	-		
Total harmonic distortion plus noise	THD + N	2.5 V, signal peak to peak voltage $R_L = 32$ $\Omega$ , $f = 1$ kHz	Room	-	-100	-		
NO, NC off capacitance <sup>d</sup>	$C_{NO(off)}$	$f = 1$ MHz		-	14.5	-	$pF$	
	$C_{NC(off)}$			-	14.5	-		
Channel-on capacitance <sup>d</sup>	$C_{NO(on)}$			-	26	-		
	$C_{NC(on)}$			-	26	-		
<b>Power Supply</b>								
Power supply range	$V_+$			1.8	-	5.5	V	
Power supply current	$I_+$	$V_{IN} = 0$ or $V_+$	Full	-	29	60	$\mu A$	

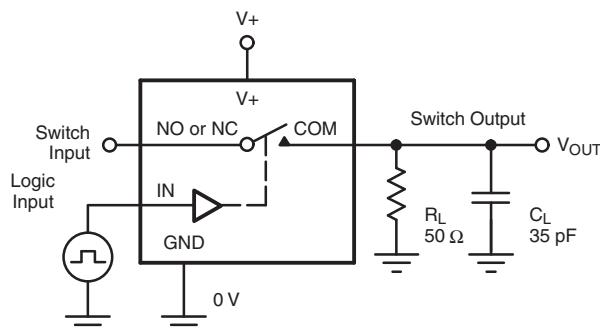
**Notes**

- a. Room = 25 °C, full = as determined by the operating suffix.
- b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
- c. Typical values are for design aid only, not guaranteed nor subject to production testing.
- d. Guarantee by design, not subjected to production test.
- e.  $V_{IN}$  = input voltage to perform proper function.
- f. Crosstalk measured between channels.

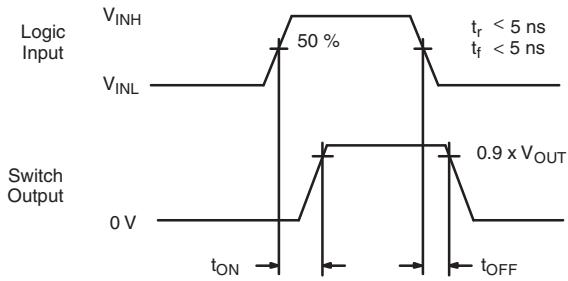
**TYPICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)


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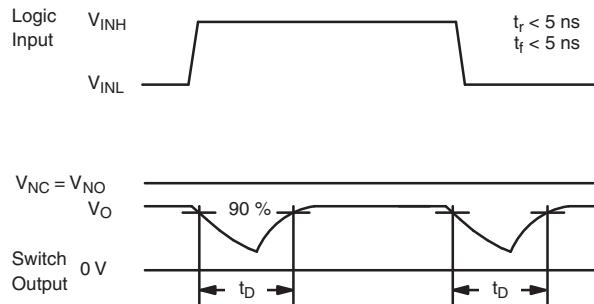
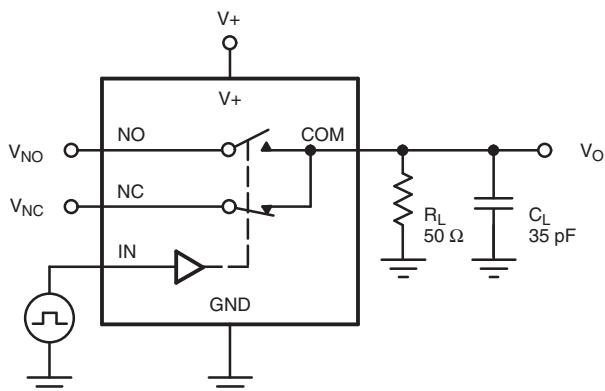
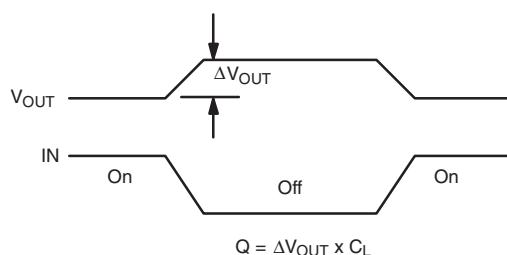
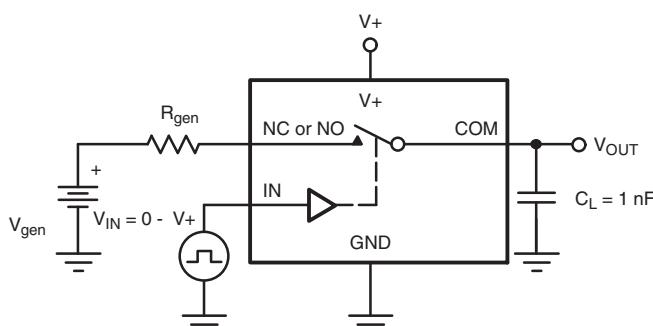
**TYPICAL CHARACTERISTICS** ( $T_A = 25^\circ\text{C}$ , unless otherwise noted)

**Charge Injection vs. Analog Voltage**

**Switching Time vs. Supply Voltage**

**Capacitance vs. Analog Voltage**

**TEST CIRCUITS**


$$V_{OUT} = V_{COM} \left( \frac{R_L}{R_L + R_{ON}} \right)$$

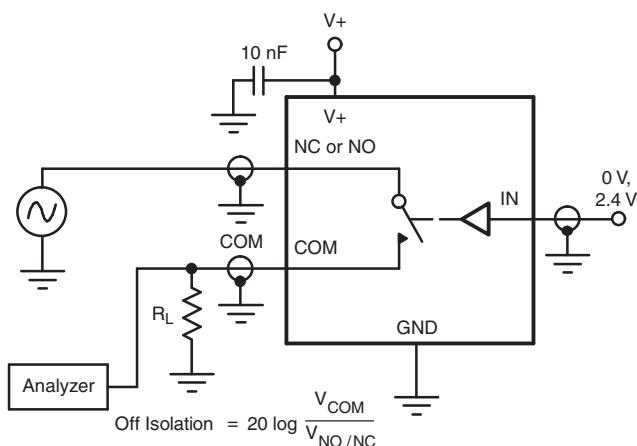


Logic "1" = Switch On  
Logic input waveforms inverted for switches that have the opposite logic sense.

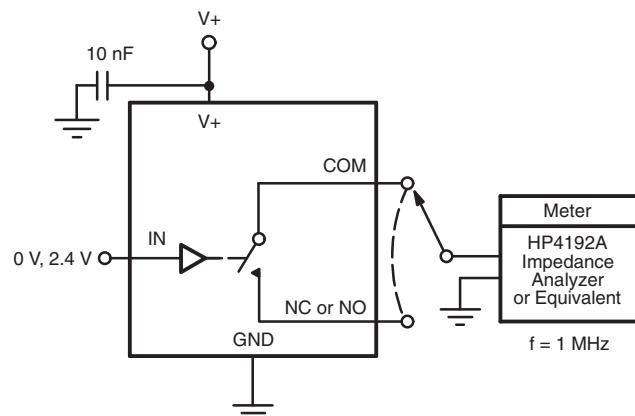
**Fig. 1 - Switching Time**

**Fig. 2 - Break-Before-Make Interval**


IN depends on switch configuration: input polarity determined by sense of switch.

**Fig. 3 - Charge Injection**



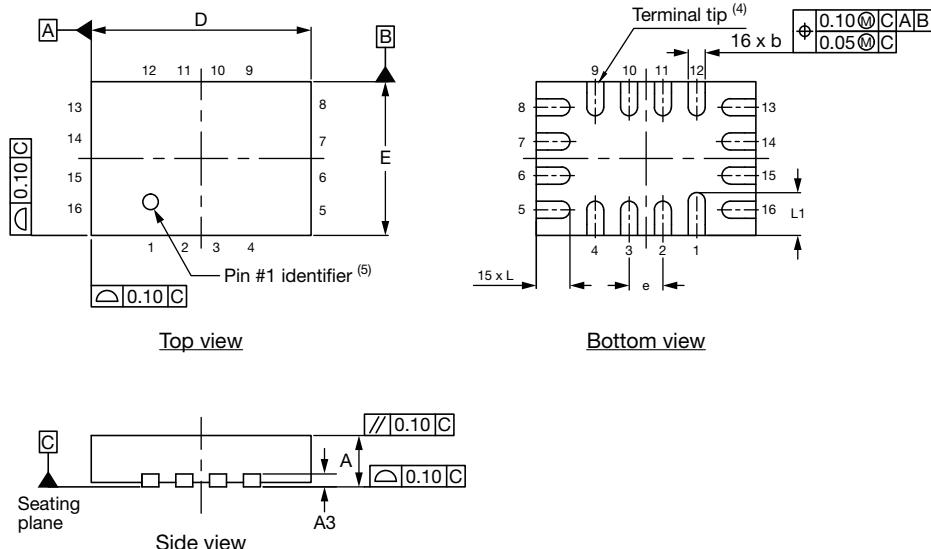
**Fig. 4 - Off-Isolation**



**Fig. 5 - Channel Off / On Capacitance**

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### Thin miniQFN16 Case Outline

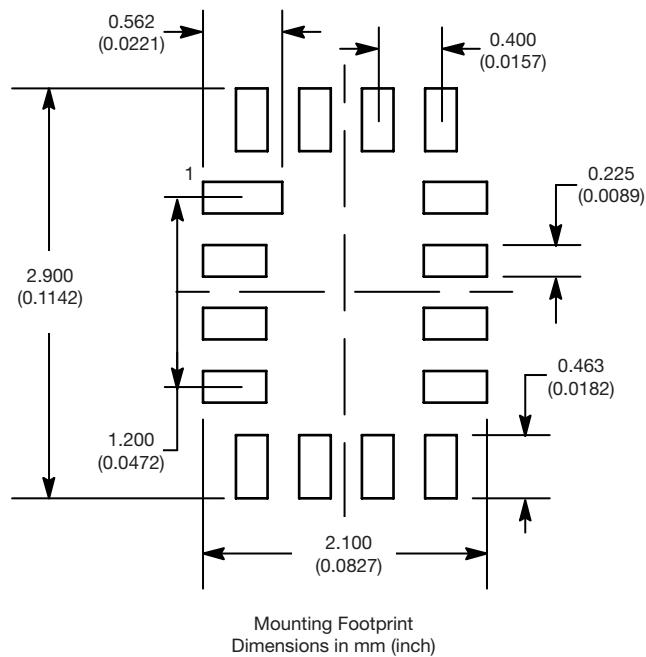


DIMENSIONS	MILLIMETERS <sup>(1)</sup>			INCHES		
	MIN.	NOM.	MAX.	MIN.	NOM.	MAX.
A	0.50	0.55	0.60	0.020	0.022	0.024
A1	0	-	0.05	0	-	0.002
A3	0.15 ref.			0.006 ref.		
b	0.15	0.20	0.25	0.006	0.008	0.010
D	2.50	2.60	2.70	0.098	0.102	0.106
e	0.40 BSC			0.016 BSC		
E	1.70	1.80	1.90	0.067	0.071	0.075
L	0.35	0.40	0.45	0.014	0.016	0.018
L1	0.45	0.50	0.55	0.018	0.020	0.022
N <sup>(3)</sup>	16			16		
Nd <sup>(3)</sup>	4			4		
Ne <sup>(3)</sup>	4			4		

#### Notes

- (1) Use millimeters as the primary measurement.
- (2) Dimensioning and tolerances conform to ASME Y14.5M. - 1994.
- (3) N is the number of terminals. Nd and Ne is the number of terminals in each D and E site respectively.
- (4) Dimensions b applies to plated terminal and is measured between 0.15 mm and 0.30 mm from terminal tip.
- (5) The pin 1 identifier must be existed on the top surface of the package by using identification mark or other feature of package body.
- (6) Package warpage max. 0.05 mm.

ECN: T16-0226-Rev. B, 09-May-16  
DWG: 6023

**RECOMMENDED MINIMUM PADS FOR MINI QFN 16L**



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